

**Inventor:** Sandhu et al.  
**Docket No.:** 3264.6US

[illegible]

FIG. 1

TITLE: LOW-RESISTANCE CONTACT TO SILICON HAVING A  
TITANIUM SILICIDE INTERFACE AND AN AMORPHOUS TITANIUM  
CARBONITRIDE BARRIER LAYER

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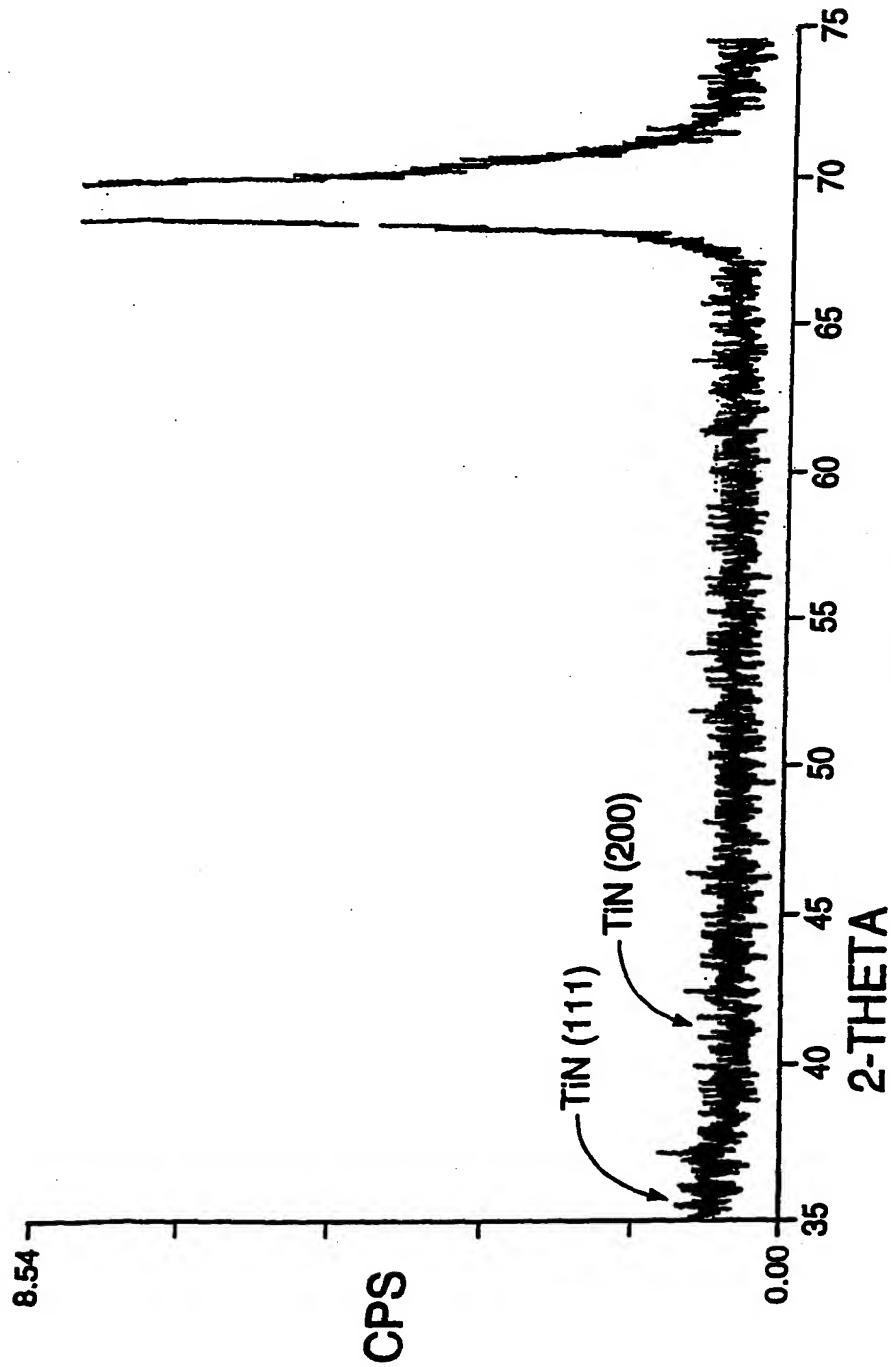


FIG. 2

TITLE: LOW-RESISTANCE CONTACT TO SILICON HAVING A  
TITANIUM SILICIDE INTERFACE AND AN AMORPHOUS TITANIUM  
CARBONITRIDE BARRIER LAYER

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